

Goodram GR2666D464L19S/4G memory module 4 GB 1 x 4 GB DDR4 288-pin DIMM

Gamintojas: **GOODRAM** · Modelis: **GR2666D464L19S/4G** · EAN: **5908267940464** · Prekės kodas: **663830**



145,90 €

Kaina su PVM

Be PVM: **120,58 €**

Sandėlyje



Prekė internetu

Nuskenaukite kodą arba apsilankykite www.shopro.lt

Pagrindinės savybės

- ✓ DIMM form factor
- ✓ supply voltage 1.2 V
- ✓ frequency: 2133, 2400, 2666, 3200 MHz
- ✓ lifetime warranty + technical support



Aprašymas

DDR4 DIMM DRAM

DDR4 memory modules are designed for the latest Intel platforms. DDR4 generation is currently the most popular format across all memory modules, chosen by users.

Ready to play

GOODRAM DDR4 memory has 4 GB, 8 GB or 16 GB of memory in one module and is available in Single and Dual Channel configurations (8, 16, 32 GB). 3200 MHz clock frequency makes GOODRAM great choice, no matter what kind of task is need to be done.

Highest quality = lifetime warranty

All GOODRAM memory modules are manufactured in Poland (Europe) with highly selected components and undergo a multi-stage quality tests before setting off for a trip to retail stores. The Quality Control Department ensures that each module is perfectly prepared for many years of use, hence we guarantee our users a lifetime warranty.

Energy efficiency & stable operation

Compared to older solutions, DDR4 modules have a 1.2 V supply voltage, which enables reduction of operating costs and increase in energy savings by up to 40%. DDR4's different PCB design vs. older generations, significantly increases the resistance to mechanical damage as well as voltage spikes within the device. As a result, DDR4 modules are characterized by reliability and stability even under the least favorable operating conditions.

Techninė specifikacija

Specifications	
Sandėlio grupė	Components & Accessories > Memory Modules/RAM [+2223][-1068]
Features	
Internal memory	4 GB
Memory layout (modules x size)	1 x 4 GB
Internal memory type	DDR4
Component for	PC/Server
Memory form factor	288-pin DIMM
ECC	No
CAS latency	19
Memory clock speed	2666 MHz
Memory channels	Single-channel
Buffered memory type	Unregistered (unbuffered)
Memory voltage	1.2 V
Module configuration	512M x 8
Weight & dimensions	
Width	133.3 mm
Packaging data	
Package type	Blister